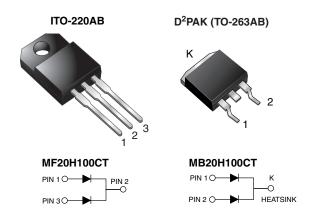


Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V _{RRM}	100 V			
I _{FSM}	250 A			
I _R	4.5 μA			
V _F	0.64			
T _J max.	175 °C			
Package	ITO-220AB, D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

Power pack

- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.

MECHANICAL DATA

Case: ITO-220AB, D²PAK (TO-263AB)

ITO-220AB Molding compound meets UL 94 V-0 flammability rating

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified ("_X" denotes revision code e.g. A, B,.....)

D²PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	MB20H100CT	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	100		
Working peak reverse voltage	V _{RWM}	100	V	
Maximum DC blocking voltage	V _{DC}	100	7	
Maximum average forward restified aureant		20		
Maximum average forward rectified current per diode	IF(AV)	10		
Peak forward surge current 8.3 ms single half sine-wave superimposed or rated load	ר I _{FSM}	250	A	
Peak repetitive reverse current per diode at $t_p = 2.0 \ \mu s$, 1 kHz	I _{RRM}	1.0		
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs	
Operating junction and storage temperature range	T _J . T _{STG}	-65 to +175	°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500	V	

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COMPLIANT

HALOGEN



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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	I _F = 10 A	T _C = 25 °C	0.77	V	
		I _F = 10 A	T _C = 125 °C	0.64		
		I _F = 20 A	T _C = 25 °C	0.88		
		I _F = 20 A	T _C = 125 °C	0.73		
Maximum reverse current at working peak reverse voltage per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	4.5	μA	
			T _J = 125 °C	6.0	mA	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MB	MF	UNIT	
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	2.0	5.8	°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	MF20H100CTHE3_B/P ⁽¹⁾	1.99	Р	50/tube	Tube
TO-263AB	MB20H100CTHM3/P ⁽¹⁾	1.35	Р	50/tube	Tube
TO-263AB	MB20H100CTHM3/I ⁽¹⁾	1.35	I	800/reel	Tape and reel

Note

(1) AEC-Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

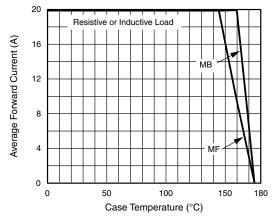


Fig. 1 - Forward Current Derating Curve

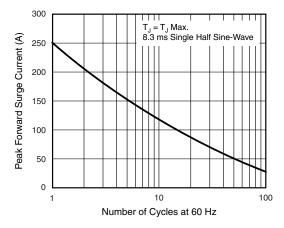
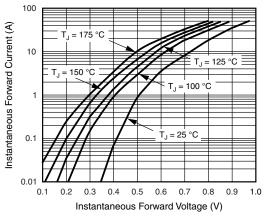
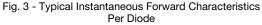


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





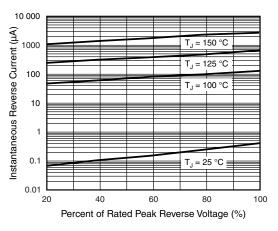


Fig. 4 - Typical Reverse Characteristics Per Diode

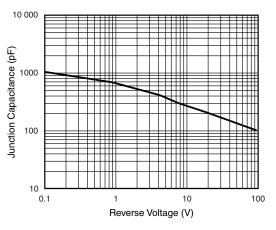


Fig. 5 - Typical Junction Capacitance Per Diode

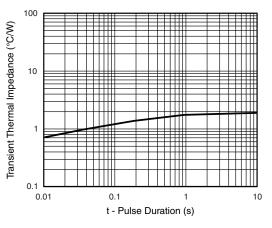


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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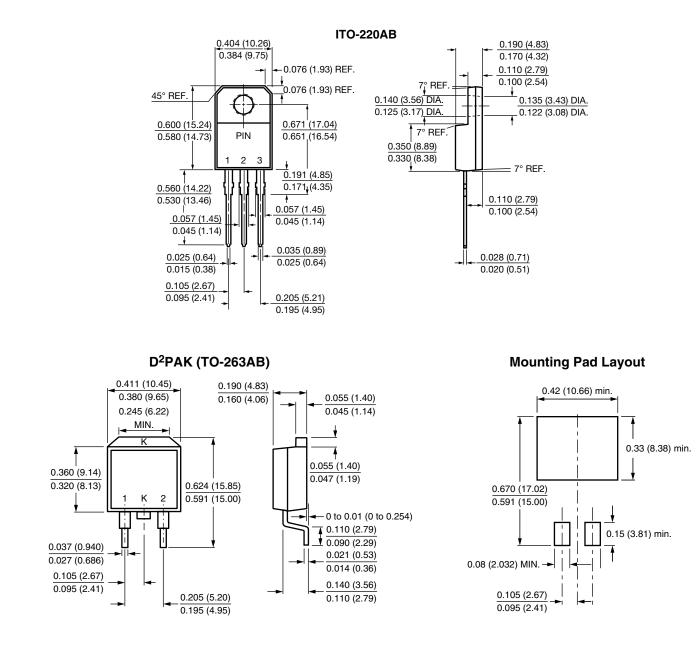
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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